## EE688 Silicon Membrane Thermal Actuator

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#### Proposed: Electro-thermal MEMS Viscometer



•In-situ P+ Si heater (joule heating).

•In-situ poly-silicon piezoresistor bridge to monitor membrane deflection

Vout=V2-V1

•Vertical displacement due to thermal coefficient of expansion difference between Si/SiO2 and Al (bimetallic effect)

•Viscosity of liquid opposes movement of membrane



## **Vertical Displacement Calibration**

- Veeco Wyko White Light Interferometer
- Measure z-displacement and Vout=V2-V1



•Images at 0, 50, 100, 150, 200 and 250m A

## **Vertical Displacement Calibration**





 $Sensitivity = 0.148 \, \mu \, m/m V/V$ 

Example, If Vbridge=5V and ? Vout=10mV, Then, ? Z=  $(5V*10mV*0.148\mu m/mV/V) = 7.4\mu m$ 



# **Dynamic Measurement**



•Thermal heater RH is pulsed with NMOS transistor to obtain needed current.

•Vout voltage is amplified with Instrumentation amplifier INA101 with a gain of 45.

# Viscosity sensor testing

Current supply to drive heater actuator to 50mA

Container if filled with oil up to set mark

Frequency of driving actuator can be changed

Amplifier can be used to reject common noise and increase signal sensitivity



# **Typical Measurement**

•Typical signal response of the amplified wheatsone bridge when the sensor is placed in oil compared to when is out it air.

•Does the change in response correspond to a change in the properties of the fluid/membrane interaction or is it just a result of the membrane not being able to heat as fast and as much as when in air?



5W30 – 115.4 cSt 10W40 – 239.4 cSt SAE60 – 758.4 cSt

•Investigate temperature of membrane in and out of oil.

## **Temperature Measurement**

Three ways to measure membrane temperature:

- 1. Thermocouples (seebeck effect)
- 2. Diode (diode temperature dependence)
- 3. Heating resistor (resistance change)



## Thermocouple delta temperature



Temperature values are theoretical predictions of temperature change. Calibration is not possible as both cold and hot junctions would be heated equally. Deflection cannot be monitored.

#### Diode delta temperature

Diode dependence on temperature Constant current, S=-2.2mV/C



No information from center of diaphragm. Deflection cannot be monitored.

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# Semiconductor resistor temperature dependence



Direct monitor of heater temperature. Z deflection can also be measured.

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#### Determine cooling effect of oil on sensor



Observe deflection at 5Hz

Measure RH (VDD/Ih) and vertical displacement in air.

Measure RH and vertical displacement in oil.

Compare results and determine whether the displacement differences are due to temperature effects or viscosity dampening.